NSN 5961-01-081-0241

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View Online at https://aerobasegroup.com/nsn/5961-01-081-0241 **Inclosure Material:** Ceramic **Overall Length:** Between 0.633 inches and 0.643 inches **Overall Height:** Between 0.125 inches and 0.135 inches Overall Width: Between 0.495 inches and 0.503 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Gate **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 120.00 milliamperes source cutoff current and 8.00 amperes source cutoff current **Power Rating Per Characteristic:** 2.2 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0